

# Fully Integrated, Hall Effect-Based Linear Current Sensor with High Voltage Isolation and a Low-Resistance Current Conductor

### **Features and Benefits**

- Monolithic Hall IC for high reliability
- Single +5 V supply
- 3 kV<sub>RMS</sub> isolation voltage between terminals 4/5 and pins 1/2/3 for up to 1 minute
- 35 kHz bandwidth
- Automotive temperature range
- End-of-line factory-trimmed for gain and offset
- Ultra-low power loss: 100  $\mu\Omega$  internal conductor resistance
- Ratiometric output from supply voltage
- Extremely stable output offset voltage
- Small package size, with easy mounting capability
- Output proportional to AC and DC currents

### Package: 5 pin module (leadform PFF)



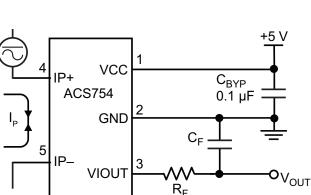
### Description

The Allegro ACS75x family of current sensors provides economical and precise solutions for current sensing in industrial, automotive, commercial, and communications systems. The device package allows for easy implementation by the customer. Typical applications include motor control, load detection and management, power supplies, and overcurrent fault protection.

The device consists of a precision, low-offset linear Hall sensor circuit with a copper conduction path located near the die. Applied current flowing through this copper conduction path generates a magnetic field which is sensed by the integrated Hall IC and converted into a proportional voltage. Device accuracy is optimized through the close proximity of the magnetic signal to the Hall transducer. A precise, proportional voltage is provided by the low-offset, chopper-stabilized BiCMOS Hall IC, which is programmed for accuracy at the factory.

The output of the device has a positive slope (>V<sub>CC</sub>/2) when an increasing current flows through the primary copper conduction path (from terminal 4 to terminal 5), which is the path used for current sensing. The internal resistance of this conductive path is typically 100  $\mu\Omega$ , providing low power loss. The thickness of the copper conductor allows survival of the device at up to

Continued on the next page ...



Application 1. The ACS754 outputs an analog signal,  $V_{OUT}$ . that varies linearly with the uni- or bi-directional AC or DC primary sensed current,  $I_P$ , within the range specified.  $C_F$  is recommended for noise management, with values that depend on the application.

## **Typical Application**

#### **Description (continued)**

 $5 \times$  overcurrent conditions. The terminals of the conductive path are electrically isolated from the sensor leads (pins 1 through 3). This allows the ACS75x family of sensors to be used in applications requiring electrical isolation without the use of opto-isolators or other costly isolation techniques.

The device is fully calibrated prior to shipment from the factory. The ACS75x family is lead (Pb) free. All pins are coated with 100% matte tin, and there is no lead inside the package. The heavy gauge leadframe is made of oxygen-free copper.

#### **Selection Guide**

	T	Primary Sensed	Sensitivity	Package			
Part Number	(°C)	Current, I <sub>P</sub> (A)	Sens (Typ.) (mV/A)	Terminals	Signal Pins	Packing <sup>1</sup>	
ACS754SCB-200-PFF	–20 to 85	±200	10	Formed	Formed	Bulk 170 pieces/bag	
ACS754SCB-200-PSF2	–20 to 85	±200	10	Straight	Formed	Bulk, 170 pieces/bag	

<sup>1</sup>Contact Allegro for additional packing options.

<sup>2</sup>Variant is in production but has been determined to be NOT FOR NEW DESIGN. This classification indicates that sale of the variant is currently restricted to existing customer applications. The variant should not be purchased for new design applications because obsolescence in the near future is probable. Samples are no longer available. Status change: April 28, 2008.

#### **Absolute Maximum Ratings**

Characteristic	Symbol	Notes	Rating	Units	
Supply Voltage	V <sub>cc</sub>		16	V	
Reverse Supply Voltage	V <sub>RCC</sub>		-16	V	
Output Voltage	V <sub>IOUT</sub>		16	V	
Reverse Output Voltage	V <sub>RIOUT</sub>		-0.1	V	
Maximum Basic Isolation Voltage	V <sub>ISO</sub>		353 VAC, 500 VDC, or V <sub>pk</sub>	V	
Maximum Rated Input Current	I <sub>IN</sub>		200	А	
Output Current Source	I <sub>OUT(Source)</sub>		3	mA	
Output Current Sink	I <sub>OUT(Sink)</sub>		10	mA	
	-	Range K	-40 to 125	°C	
Nominal Operating Ambient Temperature	T <sub>A</sub>	Range S	-20 to 85	°C	
Maximum Junction	T <sub>J</sub> (max)		165	°C	
Storage Temperature	T <sub>stg</sub>		-65 to 170	°C	



TÜV America Certificate Number: U8V 04 11 54214 001

Fire and Electric Shock EN60950-1:2001

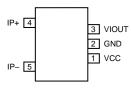




# +5 V IP+ VCC Voltage Regulator ► To all subcircuits Dynamic Offset Cancellation Filter VIOUT 0.1 μF Out Amp Temperature Gain Offset Coefficient Trim Control /7/ GND IP-**Pin-out Diagram**

#### **Functional Block Diagram**





#### **Terminal List Table**

Number	Name	Description
1	VCC	Device power supply pin
2	GND	Signal ground pin
3	VIOUT	Analog output signal pin
4	IP+	Terminal for current being sensed
5	IP-	Terminal for current being sensed



# Fully Integrated, Hall Effect-Based Linear Current Sensor with High Voltage Isolation and a Low-Resistance Current Conductor

Characteristic	Symbol	Test Conditions	Min.	Тур.	Max.	Units
Primary Sensed Current	I <sub>P</sub>		-200	_	200	A
Supply Voltage	V <sub>CC</sub>		4.5	5.0	5.5	V
Supply Current	I <sub>CC</sub>	V <sub>CC</sub> = 5.0 V, output open	6.5	8	10	mA
Output Resistance	R <sub>OUT</sub>	I <sub>OUT</sub> = 1.2 mA	-	1	2	Ω
Output Capacitance Load	C <sub>LOAD</sub>	VOUT to GND	-	_	10	nF
Output Resistive Load	R <sub>LOAD</sub>	VOUT to GND	4.7	_	_	kΩ
Primary Conductor Resistance	R <sub>PRIMARY</sub>	I <sub>P</sub> = ±50A; T <sub>A</sub> = 25°C	-	100	-	μΩ
Isolation Voltage	V <sub>ISO</sub>	Pins 1-3 and 4-5; 60 Hz, 1 minute	3.0	-	-	kV
PERFORMANCE CHARACTERIS	STICS, -20°C to	+85°C, V <sub>CC</sub> = 5 V unless otherwise spe	ecified			
Propagation time	t <sub>PROP</sub>	I <sub>P</sub> = ±100 A, T <sub>A</sub> = 25°C	-	4	_	μs
Response time	t <sub>RESPONSE</sub>	I <sub>P</sub> = ±100 A, T <sub>A</sub> = 25°C	-	11	_	μs
Rise time	t <sub>r</sub>	I <sub>P</sub> = ±100 A, T <sub>A</sub> = 25°C	_	10	_	μs
Frequency Bandwidth	f	–3 dB, T = 25°C	_	35	_	kHz
Sensitivity	Sens	Over full range of $I_P$ , $T_A = 25^{\circ}C$	-	10.0	_	mV/A
		Over full range of I <sub>P</sub>	9.5	-	10.5	mV/A
Noise	V <sub>NOISE</sub>	Peak-to-peak, T <sub>A</sub> = 25°C, no external filter	-	35	_	mV
Linearity	E <sub>LIN</sub>	Over full range of I <sub>P</sub>	-	-	±1.2	%
Symmetry	E <sub>SYM</sub>	Over full range of I <sub>P</sub>	98	100	102	%
Zero Current Output Voltage	V <sub>OUT(Q)</sub>	I = 0 A, T <sub>A</sub> = 25°C	-	V <sub>CC</sub> /2	_	V
Electrical Offset Voltage		$I = 0 A, T_A = 25^{\circ}C$	-10	-	10	mV
(Magnetic error not included)	V <sub>OE</sub>	I = 0 A	-20	-	20	mV
Magnetic Offset Error	I <sub>ERROM</sub>	I = 0 A, after excursion of 200 A	_	±0.15	±0.50	A
Total Output Error	E	Over full range of $I_P$ , $T_A = 25^{\circ}C$	_	±1.0	-	%
(Including all offsets)		Over full range of I <sub>P</sub>	_	-	±5.0	%



## **Definitions of Accuracy Characteristics**

**Sensitivity (Sens).** The change in sensor output in response to a 1 A change through the primary conductor. The sensitivity is the product of the magnetic circuit sensitivity (G/A) and the linear IC amplifier gain (mV/G). The linear IC amplifier gain is programmed at the factory to optimize the sensitivity (mV/A) for the full-scale current of the device.

**Noise (V<sub>NOISE</sub>).** The product of the linear IC amplifier gain (mV/G) and the noise floor for the Allegro Hall effect linear IC ( $\approx$ 1 G). The noise floor is derived from the thermal and shot noise observed in Hall elements. Dividing the noise (mV) by the sensitivity (mV/A) provides the smallest current that the device is able to resolve.

**Linearity** ( $\mathbf{E}_{LIN}$ ). The degree to which the voltage output from the sensor varies in direct proportion to the primary current through its full-scale amplitude. Nonlinearity in the output can be attributed to the saturation of the flux concentrator approaching the full-scale current. The following equation is used to derive the linearity:

$$100 \left\{ 1 - \left[ \frac{\Delta \text{ gain} \times \% \text{ sat } (V_{\text{IOUT}} \text{ full-scale amperes } - V_{\text{IOUT}(Q)})}{2 (V_{\text{IOUT}} \text{ half-scale amperes } - V_{\text{IOUT}(Q)})} \right] \right\}$$

where

 $\Delta$  gain = the gain variation as a function of temperature changes from 25°C,

% sat = the percentage of saturation of the flux concentrator, which becomes significant as the current being sensed approaches full-scale  $\pm I_P$ , and

 $V_{IOUT\_full-scale amperes}$  = the output voltage (V) when the sensed current approximates full-scale  $\pm I_P$ .

Symmetry ( $E_{SYM}$ ). The degree to which the absolute voltage output from the sensor varies in proportion to either a positive or negative full-scale primary current. The following equation is used to derive symmetry:

$$100 \left( \frac{V_{\text{IOUT}} + \text{ full-scale amperes } - V_{\text{IOUT}(Q)}}{V_{\text{IOUT}(Q)} - V_{\text{IOUT}} - \text{full-scale amperes}} \right)$$

**Quiescent output voltage (V**<sub>IOUT(Q)</sub>). The output of the sensor when the primary current is zero. For a unipolar supply voltage, it nominally remains at V<sub>CC</sub>/2. Thus, V<sub>CC</sub> = 5 V translates into V<sub>IOUT(Q)</sub> = 2.5 V. Variation in V<sub>OUT(Q)</sub> can be attributed to the resolution of the Allegro linear IC quiescent voltage trim, magnetic hysteresis, and thermal drift.

Electrical offset voltage ( $V_{OE}$ ). The deviation of the device output from its ideal quiescent value of  $V_{CC}/2$  due to nonmagnetic causes.

**Magnetic offset error** ( $I_{ERROM}$ ). The magnetic offset is due to the residual magnetism (remnant field) of the core material. The magnetic offset error is highest when the magnetic circuit has been saturated, usually when the device has been subjected to a full-scale or high-current overload condition. The magnetic offset is largely dependent on the material used as a flux concentrator. The larger magnetic offsets are observed at the lower operating temperatures.

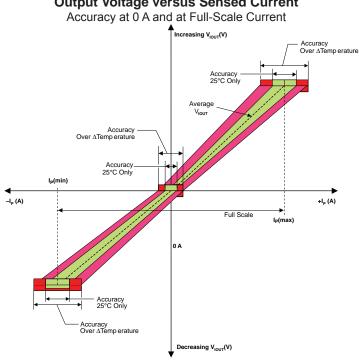
Accuracy ( $E_{TOT}$ ). The accuracy represents the maximum deviation of the actual output from its ideal value. This is also known as the total ouput error. The accuracy is illustrated graphically in the output voltage versus current chart on the following page.

Accuracy is divided into four areas:

- **0 A at 25°C.** Accuracy of sensing zero current flow at 25°C, without the effects of temperature.
- **0** A over  $\Delta$  temperature. Accuracy of sensing zero current flow including temperature effects.
- Full-scale current at 25°C. Accuracy of sensing the full-scale current at 25°C, without the effects of temperature.
- Full-scale current over  $\Delta$  temperature. Accuracy of sensing full-scale current flow including temperature effects.



Fully Integrated, Hall Effect-Based Linear Current Sensor with High Voltage Isolation and a Low-Resistance Current Conductor



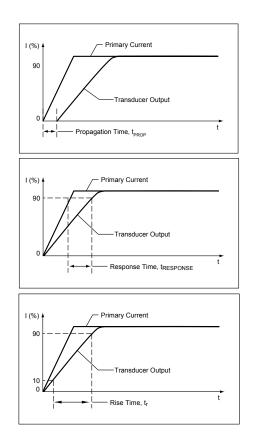
## **Output Voltage versus Sensed Current**

### **Definitions of Dynamic Response Characteristics**

Propagation delay (t<sub>PROP</sub>). The time required for the sensor output to reflect a change in the primary current signal. Propagation delay is attributed to inductive loading within the linear IC package, as well as in the inductive loop formed by the primary conductor geometry. Propagation delay can be considered as a fixed time offset and may be compensated.

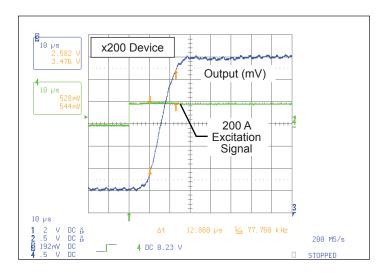
Response time (t<sub>RESPONSE</sub>). The time interval between a) when the primary current signal reaches 90% of its final value, and b) when the sensor reaches 90% of its output corresponding to the applied current.

**Rise time (t**<sub>r</sub>**).** The time interval between a) when the sensor reaches 10% of its full scale value, and b) when it reaches 90% of its full scale value. The rise time to a step response is used to derive the bandwidth of the current sensor, in which f(-3 dB) = $0.35/t_r$ . Both  $t_r$  and  $t_{RESPONSE}$  are detrimentally affected by eddy current losses observed in the conductive IC ground plane.





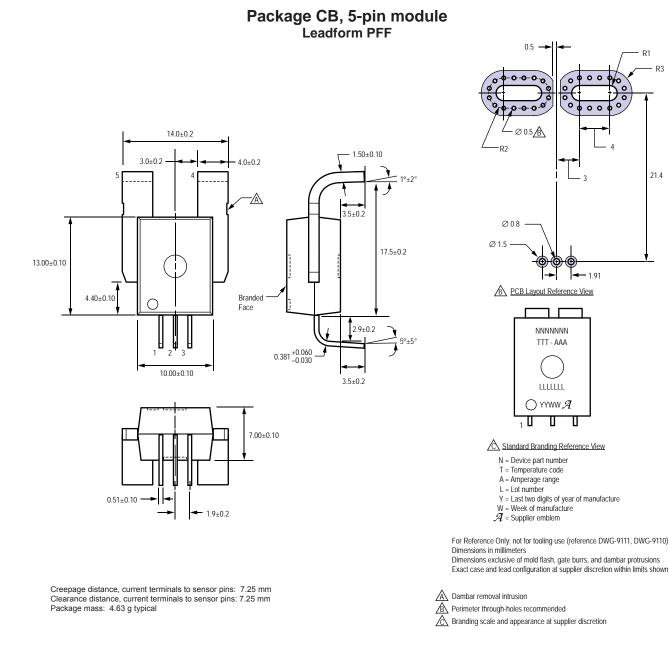
Fully Integrated, Hall Effect-Based Linear Current Sensor with High Voltage Isolation and a Low-Resistance Current Conductor



Step Response No external filter, T<sub>A</sub>=25°C



# Fully Integrated, Hall Effect-Based Linear Current Sensor with High Voltage Isolation and a Low-Resistance Current Conductor



Copyright ©2004-2009, Allegro MicroSystems, Inc.

The products described herein are manufactured under one or more of the following U.S. patents: 5,045,920; 5,264,783; 5,442,283; 5,389,889; 5,581,179; 5,517,112; 5,619,137; 5,621,319; 5,650,719; 5,686,894; 5,694,038; 5,729,130; 5,917,320; and other patents pending.

Allegro MicroSystems, Inc. reserves the right to make, from time to time, such departures from the detail specifications as may be required to permit improvements in the performance, reliability, or manufacturability of its products. Before placing an order, the user is cautioned to verify that the information being relied upon is current.

Allegro's products are not to be used in life support devices or systems, if a failure of an Allegro product can reasonably be expected to cause the failure of that life support device or system, or to affect the safety or effectiveness of that device or system.

The information included herein is believed to be accurate and reliable. However, Allegro MicroSystems, Inc. assumes no responsibility for its use; nor for any infringement of patents or other rights of third parties which may result from its use.

For the latest version of this document, visit our website:

www.allegromicro.com



R3

21.4